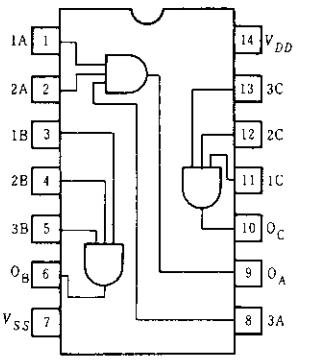
HD14073B

Triple 3-input AND Gate

■ PIN ARRANGEMENT

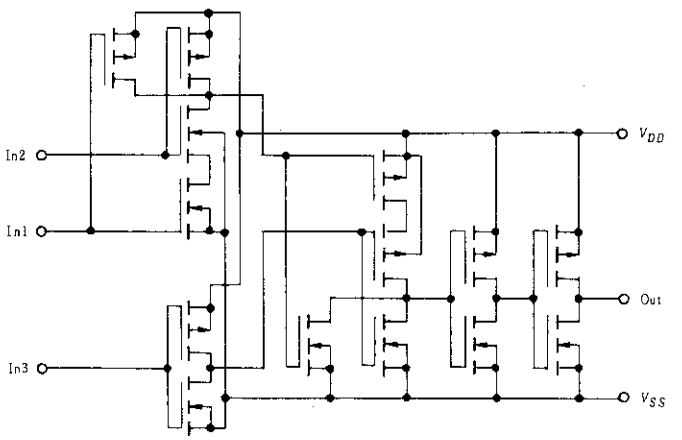


(Top View)

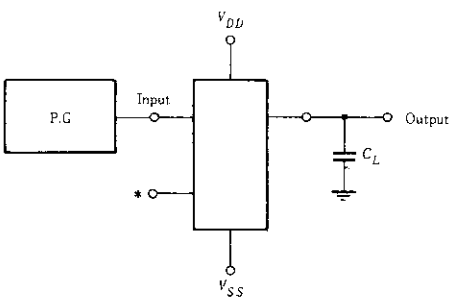
■ FEATURES

- Quiescent Current = 0.5nA typ/pkg @5V
- Noise Immunity = 45% of V_{DD} typ
- Capable of Driving One Low-power Schottky TTL Load Over the Rated Temperature Range
- Pin-for Pin Replacements for CD4073B and MC14073B Series

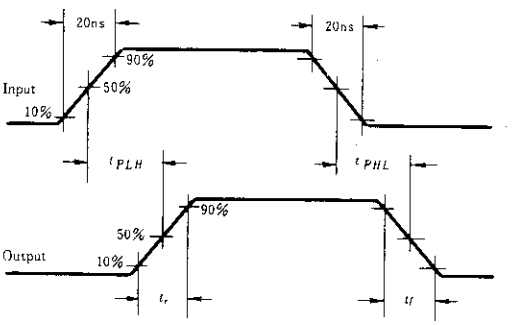
■ CIRCUIT SCHEMATIC (1/3)



■ SWITCHING TIME TEST CIRCUIT



* All unused inputs of AND, NAND gates must be connected to V_{DD}



■ ELECTRICAL CHARACTERISTICS

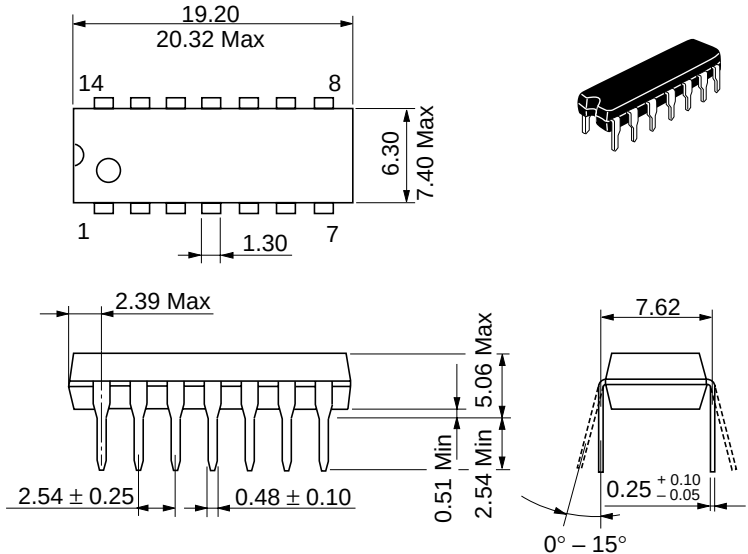
Characteristic	Symbol	V_{DD}(V)	Test Conditions	−40°C min	−40°C max	25°C min	25°C typ	25°C max	85°C min	85°C max	Unit
Output Voltage	V_{OL}	5.0	V_{in}= 0	—	0.05	—	0	0.05	—	0.05	V
		10		—	0.05	—	0	0.05	—	0.05	
		15		—	0.05	—	0	0.05	—	0.05	
	V_{OH}	5.0	$V_{in}=V_{DD}$	4.95	—	4.95	5.0	—	4.95	—	V
		10		9.95	—	9.95	10	—	9.95	—	
		15		14.95	—	14.95	15	—	14.95	—	
Input Voltage	V_{IL}	5.0	V_{out}=0.5V	—	1.5	—	2.25	1.5	—	1.5	V
		10	V_{out}=1.0V	—	3.0	—	4.50	3.0	—	3.0	
		15	V_{out}=1.5V	—	4.0	—	6.75	4.0	—	4.0	
	V_{IH}	5.0	V_{out}=4.5V	3.5	—	3.5	2.75	—	3.5	—	V
		10	V_{out}=9.0V	7.0	—	7.0	5.50	—	7.0	—	
		15	V_{out}=13.5V	11.0	—	11.0	8.25	—	11.0	—	
Output Drive Current	I_{OH}	5.0	V_{OH}=2.5V	−2.5	—	−2.1	−4.2	—	−1.7	—	mA
		5.0	V_{OH}=4.6V	−0.52	—	−0.44	−0.88	—	−0.36	—	
		10	V_{OH}=9.5V	−1.3	—	−1.1	−2.25	—	−0.9	—	
		15	V_{OH}=13.5V	−3.6	—	−3.0	−8.8	—	−2.4	—	
	I_{OL}	5.0	V_{OL}=0.4V	0.52	—	0.44	0.88	—	0.36	—	mA
		10	V_{OL}=0.5V	1.3	—	1.1	2.25	—	0.9	—	
		15	V_{OL}=1.5V	3.6	—	3.0	8.8	—	2.4	—	
Input Current	I_{in}	15		—	±0.3	—	±0.00001	±0.3	—	±1.0	μA
Input Capacitance	C_{in}	—	V_{in}= 0	—	—	—	5.0	7.5	—	—	pF
Quiescent Current	I_{DD}	5.0	Zero Signal, per Package	—	1.0	—	0.0005	1.0	—	7.5	μA
		10		—	2.0	—	0.0010	2.0	—	15.0	
		15		—	4.0	—	0.0015	4.0	—	30.0	
Total Supply Current*	I_T	5.0	Dynamic $-I_{DD}$, C_L=50pF per Gate, f=1kHz	—	—	—	0.3	—	—	—	μA
		10		—	—	—	0.6	—	—	—	
		15		—	—	—	0.9	—	—	—	

* To calculate total supply current at frequency other than 1kHz.
@ V_{DD}=5.0V I_T=(0.3μA/kHz)f−I_{DD}/3 @ V_{DD}=10V I_T=(0.6μA/kHz)f+I_{DD}/3 @ V_{DD}=15V I_T=(0.9μA/kHz)f+I_{DD}/3

■ SWITCHING CHARACTERISTICS (C_L=50pF, Ta=25°C)

Characteristic	Symbol	V_{DD}(V)	min	typ	max	Unit
Output Rise Time	t_r	5.0	—	100	200	ns
		10	—	50	100	
		15	—	40	80	
Output Fall Time	t_f	5.0	—	100	200	ns
		10	—	50	100	
		15	—	40	80	
Propagation Delay Time	t_{PLH}	5.0	—	160	320	ns
		10	—	65	130	
		15	—	50	100	
	t_{PHL}	5.0	—	160	320	ns
		10	—	65	130	
		15	—	50	100	

Unit: mm



Hitachi Code	DP-14
JEDEC	Conforms
EIAJ	Conforms
Weight (reference value)	0.97 g

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